

General Description

Maxim's MX581 is a three-terminal, temperaturecompensated, bandgap voltage reference which provides a precision 10V output from an unregulated input of 12.5V to 30V. Laser trimming is used to minimize initial error and temperature drift, to as low as 10mV and 15ppm/°C with the MX581.

No external components are needed to achieve full accuracy over the operating temperature range. Total supply current to the device, including the internal output buffer amplifier is typically 750µA.

The MX581 is designed for use with 8- to 14-bit ADCs and DACs as well as data acquisition systems. The reference is available in a 3-pin T0-39 metal can and an 8-pin SO surface-mount package.

Applications

CMOS DAC Reference A/D Converter Reference Measurement Instrumentation Threshold Detectors Precision Analog Systems

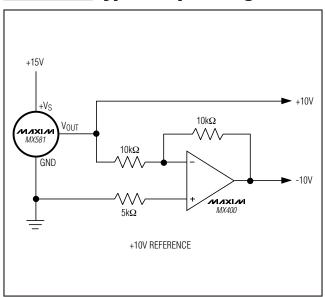
Features

- ♦ ±10mV Tolerance (MX581K)
- ♦ Low Tempco—15ppm/°C max (MAX581K)
- ♦ No External Components or Trims
- **♦ Short-Circuit Proof**
- **♦ Output Sources and Sinks Current**
- **♦ 10mA Output Current**
- ♦ Low-Supply Current—1.0mA (max)
- **♦ Three-Terminal Package**

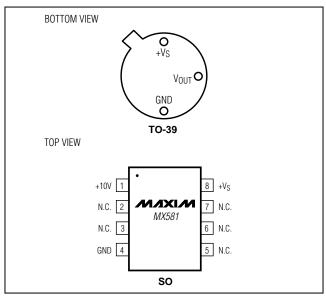
Ordering Information

PART	TEMP RANGE	PIN- PACKAGE	ERROR
MX581JH	0°C to +70°C	3 TO-39 Can	±30mV
MX581KH	0°C to +70°C	3 TO-39 Can	±10mV
MX581JCSA	0°C to +70°C	8 SO	±30mV
MX581KCSA	0°C to +70°C	8 SO	±10mV
MX581JESA	-40°C to +85°C	8 SO	±30mV
MX581KESA	-40°C to +85°C	8 SO	±10mV
MX581SH	-55°C to +125°C	3 TO-39 Can	±20mV
MX581TH	-55°C to +125°C	3 TO-39 Can	±10mV

Typical Operating Circuit



Pin Configurations



NIXIN

Maxim Integrated Products 1

ABSOLUTE MAXIMUM RATINGS

Input Voltage (V _{IN} to GND) Continuous Power Dissipation	0.3V, +40V	Storage Tempera Lead Temperature
TO-39 Can (derate 8.7mW/°C above -	+60°C)600mW	Die Junction Tem
SO (derate 5.3mW/°C above +75°C)		Thermal Resistan
Output Short-Circuit Duration (Note 1)	Indefinite	TO-39 CAN
Operating Temperature Range		SO
Commercial (J, K)	0°C to +70°C	
Extended (J, K)	40°C to +85°C	
Military (S, T)	55°C to +125°C	

Storage Temperature Range	65°C to +175°C
Lead Temperature (soldering, 10s)	+300°C
Die Junction Temperature (TJ)	
Thermal Resistance, Junction to Ambient	
TO-39 CAN	+150°C/W
SO	+170°C/W

Note 1: Absolute maximum power dissipation must not be exceeded.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

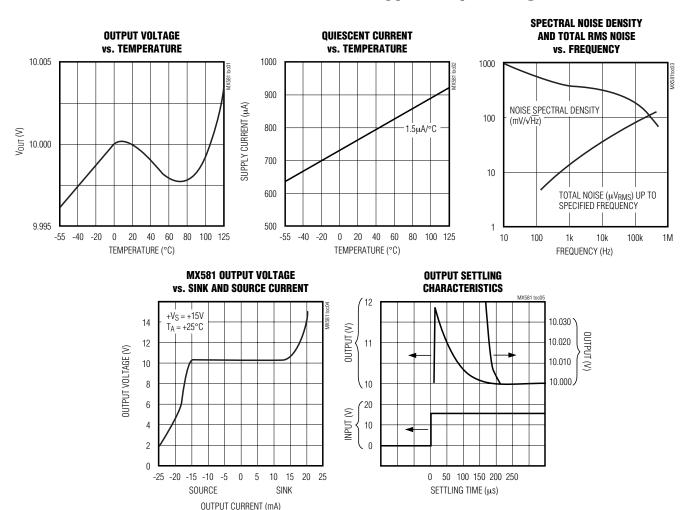
ELECTRICAL CHARACTERISTICS

 $(V_{IN} = +15V. T_A = +25^{\circ}C$, unless otherwise noted.)

PARAI	METER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS	
Output Voltage Tolerance			IL = 0mA	MX581J/S				30	mV
			IL = OITIA	MX581K/T				±10) mv
Output Voltage Change with Temperature (Temperature Coefficient)			MX581JH/JCSA				13.5 (30)	mV (ppm/°C)	
			MX581JESA MX581KH/KCSA MX581KESA MX581S				19.5 (30)		
							6.75 (15)		
							13 (20)		
							30 (30)		
			MX581T				15 (15)		
Line Regulation			No load	12.5V < V _{IN} <	15V	0.005 (1.0)		%/V	
		IN	No load	15V < V _{IN} < 30	V			0.002 (3.0)	(mV)
Load Regulation			I _L = 0mA to 5mA			20 (220)	50 (550)	ppm/mA (µV/mA)	
Quiescent Supply	y Current	IQ	$I_L = 0mA$			750	1000	μΑ	
Turn-On Settling	Time to 0.1%	ton				200		μs	
Noise		en(P-P)	0.1Hz to 10Hz			50		μV _{P-P}	
Long-Term Stabi	lity		Noncumulative			25		ppm/kHrs	
Short-Circuit Cur	rent	Isc				30		mA	
Output Current	Source	IL.	V _{IN} > V _{OUT} + 2.5V	T _A = +25°C		10			
				T _{MIN} to T _{MAX}		5			
				T _{MIN} to T _{MAX}	MX581J/K	5			mA
	Sink (Note 2)				MX581S/T	0.2			
				$T_A = -55$ °C to $+65$ °C	MX581S/T	5			

Note 2: $C_{LOAD} \ge 10nF$ (see the *Output Current* section).

Typical Operating Characteristics



Detailed Description

As shown in Figure 1, most applications of the MX581 require no external components. Connections are +VS, VOUT, and GND (GND is tied to the case in the TO-5 package). Usually the desired accuracy is obtained by selecting the appropriate device grade. However, any part can be adjusted to a tighter tolerance, or to slightly different voltage, using the fine trim circuit in Figure 2. The table in Figure 2 lists the trim range for different values of R in the figure, and also shows the effect on temperature coefficient.

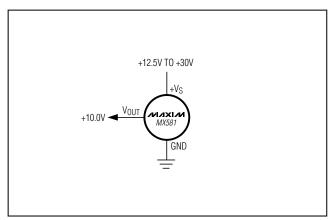


Figure 1. MX581 Basic Connection

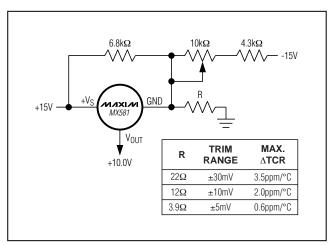


Figure 2. Optional Fine Trim Configuration

Voltage Temperature Coefficient

The temperature characteristic of the MX581 consistently follows an "S-curve" (see *Typical Operating Characteristics*). A five-point 100% test guarantees compliance with -55°C to +125°C specifications and a three-point 100% test guarantees 0°C to +70°C specifications.

The voltage change specifications in the *Electrical Characteristics* table state the maximum deviation over temperature from the reference's initial value at +25°C, as well as drift in ppm/°C. By adding the maximum deviation for a given device to its initial tolerance, the total error is quickly determined.

Output Current

The MX581 is unique in that it can sink as well as source current. The circuit is also protected for output shorts to either +VS or GND. The output voltage versus current characteristic is shown in the *Typical Operating Characteristics*. For applications that require the MX581 to sink current, maintain a load capacitance of 10nF or greater for proper operation.

Dynamic Performance

The turn-on characteristic and settling performance of the MX581 are shown in the *Typical Operating Characteristics*. Both coarse and fine transient response is shown. The reference typically settles to 1mV within 180µs after power is applied.

Applications Information

Precision High-Current Reference

A pnp power transistor, or Darlington, is easily connected to the MX581 to greatly increase its output current. The circuit of Figure 3 provides a +10V output at up to 4A. If the load has a significant capacitive component, compensation capacitor, C1, should be added. If the load is purely resistive, high-frequency supply rejection is improved without C1.

Low Input Voltage

Although line regulation is specified from 12.5V to 40V, the MX581 can operate with a $+12V \pm 5\%$ input by adding a resistor as shown in Figure 4. The resistor reduces the current that must be supplied from V_{OUT}. Note that the resistor cannot be used at higher input voltages since, as the supply increases, it sources more current than V_{OUT} can sink.

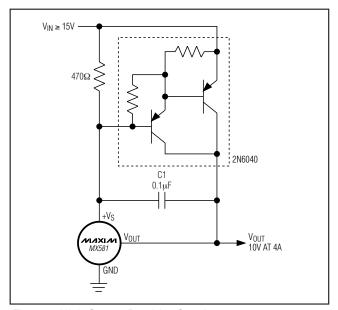


Figure 3. High-Current Precision Supply

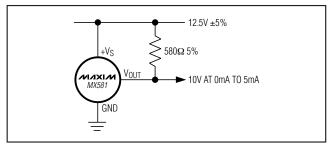


Figure 4. 12V Supply Connection

Current Limiter

By adding a single resistor as shown in Figure 5, the MX581 is turned into a precision current limiter for applications where the driving voltage is 12.5V to 40V. The programmed current ranges from 0.75mA to 5mA.

Negative 10V Reference

Where a -10V reference is required, the MX581 can be connected as a two-terminal device and biased like a zener diode. The circuit is shown in Figure 6. +Vs and Vout are connected to the system's analog ground and the MX581's GND pin is connected, through a resistor, to the negative supply. With 1mA flowing in the reference, the output voltage is typically 2mV greater than what is obtained with the conventional, positive hook-up.

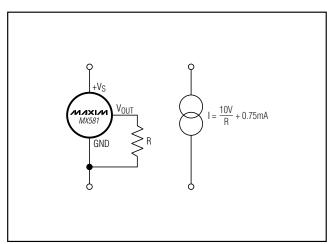


Figure 5. Two-Component Precision Current Limiter

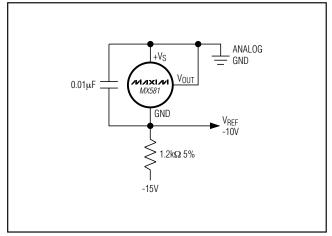


Figure 6. Two-Terminal -10V Reference

When using the 2-terminal connection, the load and the bias resistor must be selected so that the current flowing in the reference is maintained between 1mA and 5mA. The operating temperature range for this connection is limited to -55°C to +85°C.

Reference for CMOS DACs and ADCs

The MX581 is well suited for use with a wide variety of digital-to-analog converters, especially CMOS DACs. Figure 7 shows a circuit in which an MX7533 10-bit DAC outputs 0 to -10V when using a +10V reference. For a positive DAC output, the MX581 is configured as a 2-terminal -10V reference (Figure 6) and connected to the DAC's VREF input.

In Figure 8, an MX7574 CMOS ADC uses an MX581 for its -10V reference input. The input range for the ADC is 0 to +10V.

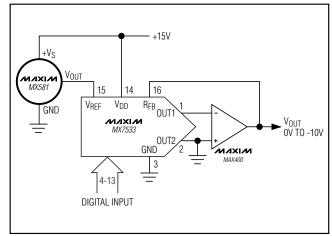


Figure 7. Low-Power, 10-Bit CMOS DAC Connection

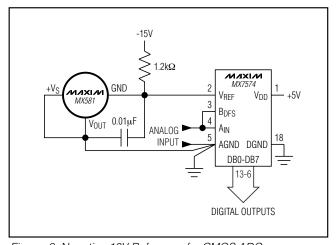


Figure 8. Negative 10V Reference for CMOS ADC

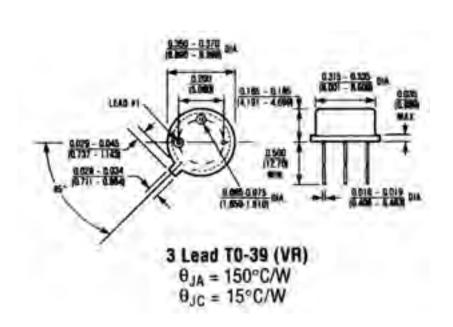
+15V +Vs Vout 2 MX581 GND 1/3 74C240 3-STATE BUFFER

Figure 9. MX581 Microprocessor Interface

-V_S - (2.208mm) - (2.208mm) - (1.803mm)

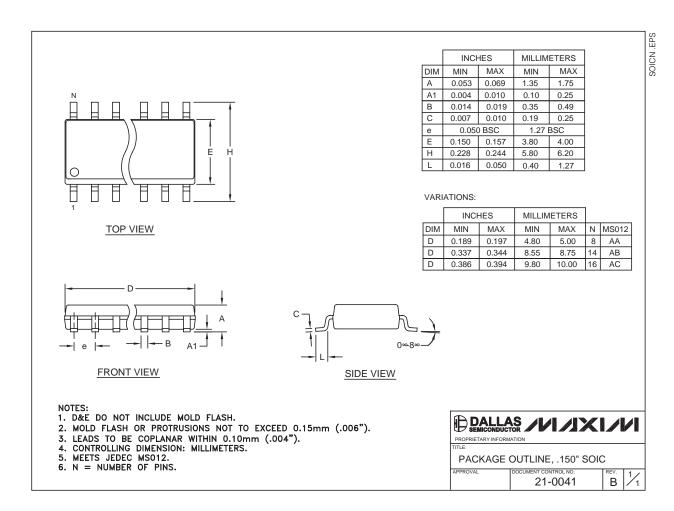
Chip Topography

TRANSISTOR COUNT: 72 SUBSTRATE CONNECTED TO GND



Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



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